Metric Prefixes

peta	P	10^{15}	1 000 000 000 000 000
tera	T	10^{12}	1 000 000 000 000
giga	G	10^9	1 000 000 000
mega	M	10^6	1 000 000
kilo	k	10^3	1 000
hecto	h	10^2	100
deca	da	10^1	10
one		10^0	1
deci	d	10^{-1}	0.1
centi	c	10^{-2}	0.01
milli	m	10^{-3}	0.001
micro	μ	10^{-6}	0.000 001
nano	n	10^{-9}	0.000 000 001
pico	p	10^{-12}	0.000 000 000 001
femto	f	10^{-15}	0.000 000 000 000 001

Ohm's Law $V = IR, \quad I = \frac{V}{R}, \quad R = \frac{V}{I}$
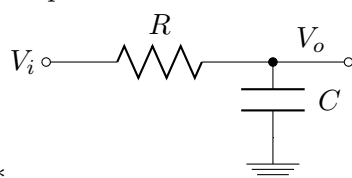
Complex Numbers

- $z = x + iy = re^{i\theta} = r[\cos(\theta) + i\sin(\theta)]$
- $[r(\cos(\theta) + i\sin(\theta))]^n = r^n[\cos(n\theta) + i\sin(n\theta)]$
- $z^n = (re^{i\theta}) = r^n e^{in\theta}$
- $\frac{1}{i} = -i$
- $\sqrt[n]{z} = \sqrt[n]{r}e^{\frac{\theta}{n} + \frac{2k\pi}{n}}$ for $n \in N^*$ (ints ≥ 0)
- $e^{j\theta} = \cos(\theta) + j\sin(\theta)$
- $e^{-j\theta} = \cos(\theta) - j\sin(\theta)$
- $\cos(\theta) = \frac{1}{2}(e^{j\theta} + e^{-j\theta})$
- $\sin(\theta) = \frac{1}{2j}(e^{j\theta} - e^{-j\theta})$
- normalized: $sinc(t) = \frac{\sin(\pi t)}{\pi t}$
- $|\frac{a}{b}| = \frac{|a|}{|b|}$
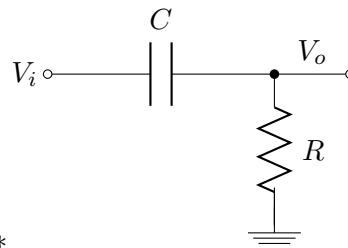- $\angle\frac{a}{b} = \angle a - \angle b$

Trig

- $\cos^2(a) + \sin^2(a) = 1$
- $\cos(2a) = \cos^2(a) - \sin^2(a) = 2\cos^2(a) - 1 = 1 - 2\sin^2(a)$
- $\sin(2a) = 2\sin(a)\cos(a)$
- $\cos^2(a) = \frac{1}{2}(1 + \cos(2a))$
- $\sin^2(a) = \frac{1}{2}(1 - \cos(2a))$

RC Filter

- Transmission Function: $T(s) = \frac{V_o(s)}{V_i(s)}$
- Corner frequency: frequency s at which $T(s) = \frac{1}{\sqrt{2}}$
- for simple circuit: ground→source→ $R \to C$ →ground
  * $T(s) = \frac{1}{1+RCs}$
  $|T(j\omega)| = \frac{1}{\sqrt{1+R^2C^2s^2}}$
  $|\angle T(j\omega)| = \frac{1}{\sqrt{1+R^2C^2s^2}}$
- low pass

- *
  * $T(s) = \frac{V_o}{V_i} = \frac{1}{1+RCs}$
  * corner frequency: $s = \frac{1}{RC}$ (also pole)
  * pole: $\frac{1}{RC}$
- high pass

- *
  * $T(s) = \frac{V_o}{V_i} = \frac{RCs}{1+RCs}$
  * zero: $s = 0$, pole: $s = \frac{1}{RC}$

Bode Plots

- magnitude is plotted in dB:
  $|T(j\omega)|_{dB} = 20\log_{10}|T(j\omega)|$
- starts on y-axis at DC offset with slope 0
- just add together the bode plots of each individual pole, zero, and the DC offset
- poles always slope down, zeros slope up (applies for both magnitude and phase)
- dec=decade, e.g. from 10^0 to 10^1
- magnitude:
  * Pole/Zero at origin:
    constant slope $\pm 20db/dec$ for all ω; $0dB$ at $\omega = 10^0 = 1$
  * Pole/Zero at ω_0:
    0 for $\omega < \omega_0$
    slope $\pm 20\frac{db}{dec}$ after
  * Constant C: constant line at $20\log_{10}(|C|)$
- phase:
  * Pole at origin: constant $-\frac{\pi}{2}$ or $-90°$
  * Zero at origin: constant $+\frac{\pi}{2}$ or $+90°$
  * Pole/Zero at ω_0:
    0 for $\omega < \frac{\omega_0}{10}$
    slope linearly ($\pm 45°/dec$) until $10\omega_0$
    0 slope for $\omega > 10\omega_0$
  * Constant C: no effect (0 for all ω)
- Prof wants us to actually show the -3dB drop curve, not just a straight intersection

Solving systems with Op Amps

- step 0: if the op amp is ideal, write out ideal properties:
  * $V_+ = V_-$
  * $I_- = 0, I_+ = 0$
  * $A \approx \infty$
- avoid doing KCL/KVL directly on the output node of the op amp
- ignore resistors from a point at $0V$ to ground

Non-Ideal Op Amps

- still assume that current at input terminals is 0
- $V_o = A(V_+ - V_-)$
  * A: open-loop gain. Typically very large, 100,000 or more
- open-loop gain dependent on frequency: $A(s) = \frac{A_0}{1 - \frac{s}{\omega_b}}$
  * open-loop response drops off after ω_b (usually $2\pi \leq \omega_b \leq 2\pi 100$)
  * A_0: DC gain
  * ω_t: unity gain frequency: $dB(T(\omega_t)) = 1$
    $\omega_t \approx A_o\omega_b$
    AKA gain bandwidth product
  * in this case, we still assume $I_- = I_+ = 0$ and $V_- = V_+$?
- slew rate
  * max rate at which the output can change
  * for a sinusoidal signal: (V_{pk}: peak voltage)
    $SR > 2\pi f V_{pk}$ or $SR > \omega V_{pk}$
    $\frac{dV_o}{dt}|_{MAX} < SR$

Op Amp Equations

- general form: $T(s) = \frac{K_0}{1+\frac{s}{\omega_0}}$
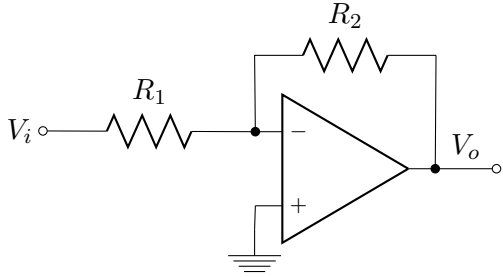 * $T(0) = K_0$: DC offset. For these simple ones, it's equal to ideal response
  * $\omega_0 = \frac{\omega_t}{1+R_2/R_1}$
- inverting op amp:
  * ideal: $T(s) = \frac{V_o}{V_i} = -\frac{R_2}{R_1}$
  * non-ideal:
    $T(s) = \frac{V_o}{V_i} = \frac{-R_2/R_1}{1+\frac{1+R_2/R_1}{A(s)}} = \frac{-R_2/R_1}{1+\frac{s}{\left(\frac{\omega_t}{1+R_2/R_1}\right)}} = \frac{-R_2/R_1}{1+\frac{s}{\omega_0}}$
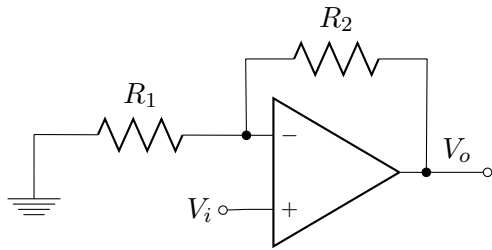

- non-inverting op-amp:
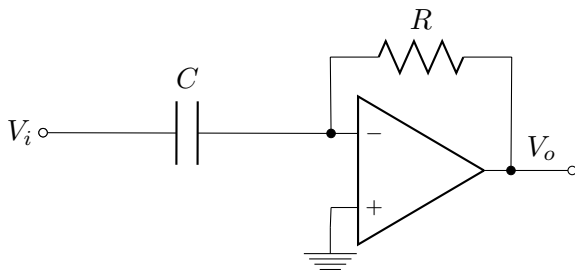 * ideal: $T(s) = \frac{V_o}{V_i} = 1 + \frac{R_2}{R_1}$
  * non-ideal:
    $T(s) = \frac{V_o}{V_i} = \frac{1+R_2/R_1}{1+\frac{1+R_2/R_1}{A(s)}} = \frac{1+R_2/R_1}{1+\frac{s}{\left(\frac{\omega_t}{1+R_2/R_1}\right)}} = \frac{1+R_2/R_1}{1+\frac{s}{\omega_0}}$
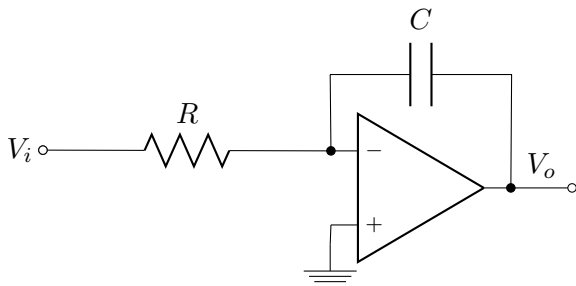

- integrating
  * ideal: $V_o = -\int_0^t \frac{V_i}{RC}dt + C$
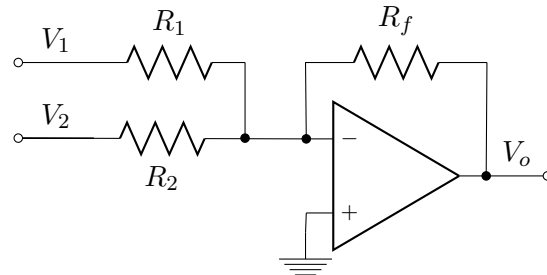 = $C = V_o(t)$ at $t = 0$

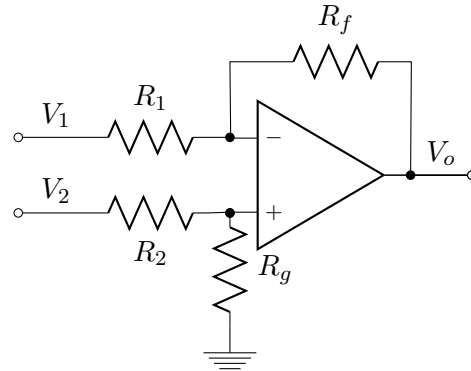- differentiating
  * ideal: $V_o = -RC\frac{dV_i}{dt}$

- summing
  * ideal: $V_o = -R_f\left(\frac{V_1}{R_1} + \frac{V_2}{R_2}\right)$

- differential (subtracting)
  * ideal: $V_o = \frac{(R_f+R_1)R_g}{(R_g+R_2)R_1}V_2 - \frac{R_f}{R_1}V_1$

Diodes

- $I_D = I_S\left(e^{\frac{V_D}{nV_T}} - 1\right)$
  * $I_S = 10^{-12}$A (saturation current)
  * $V_T = 25$mV
- small signal resistance: $R_D = \frac{nV_T}{I_D}$
  * I_D: average (DC) current through diode (due to forward bias)
- bridge rectifier shape: all the diodes point toward the + end of the output (away from ground)

Design an (unregulated) AC adapter

- V_S: AC voltage input
- V_{S2}: output of transformer (still AC)
- V_p: peak DC output
  * V_r: peak-to-peak ripple voltage (maximum variation)
- $V_p = V_{S2} -$ (diode voltage)
  * diode voltage = 0.7V for single wave rectifier or center-tapped transformer
  * diode voltage = 1.4V for full-wave rectifier
- turns ratio = $n = \frac{V_S}{V_{S2}}$
- apparent load resistance: $R_L = \frac{V_o}{I_L}$
- ripple voltage: $V_r = \frac{f}{R_L C}$
  * f: actual ripple frequency (double for full-wave rectifier)
  * C: filter cap size
- Peak Inverse Voltage: $PIV = V_{S2} - 0.7V$
- avg diode current: $I_{Davg} = I_L\left(1 + \pi\sqrt{\frac{2}{V_r}}\right)$
- max diode current: $I_{Dmax} = I_L\left(1 + 2\pi\sqrt{\frac{2}{V_r}}\right)$
  * only difference is $\pi \to 2\pi$

Transistors

- $V_T = 25$mV at room temperature (according to textbook and prof),
  $V_T = 26$mV at room temperature (according to lab)
- β: a physical constant of the transistor. Usually about 100 or 200
- $I_B + I_C = I_E$, $I_C = \beta I_B$, $I_E = (1+\beta)I_B$
- $\alpha = \frac{\beta}{1+\beta}$, $I_C = \alpha I_E$

- $I_C = I_S(e^{\frac{V_{BE}}{nV_T}})$,
- AC (assumes correct DC bias): $g_m = \frac{1}{r_e} = \frac{I_C}{V_T}$

Transistor circuits by inspection

- this all assumes that the transistor is properly DC biased
- three types of amplifier circuits: common emitter, common base, common collector
  * CE, CB, CC
  * the "common" pin is the one that is neither AC input nor output
- intrinsic gain: gain directly from the input pin of the transistor to the output, ignoring any source resistance or such things whatever
  * when you chain multiple amplifiers together, this is the one you use
- when you're driving a finite-impedance load (a load other than open circuit), you have to consider R_o as $R_o||R_L$
  * this will change the gain, which is why it's often helpful to put a CC buffer at the end of an amplifier
- R_i: input impedance: impedance as seen from the input
  * includes the transistor, does not include R_s
- CE: Common Emitter
  * input: base; output: collector
  * intrinsic gain: $\frac{V_o}{V_i} = -\alpha\frac{R_C}{r_e+R_E} \approx -\frac{R_C}{r_e+R_E}$
  * $R_o = R_C$